

S James Allen

List of Publications by Year in descending order

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32

papers

1,631

citations

346980

22

h-index

511568

30

g-index

32

all docs

32

docs citations

32

times ranked

2559

citing authors

#	ARTICLE	IF	CITATIONS
1	Non-Fermi liquids in oxide heterostructures. Reports on Progress in Physics, 2018, 81, 062502.	8.1	21
2	Conduction band edge effective mass of La-doped BaSnO ₃ . Applied Physics Letters, 2016, 108, .	1.5	39
3	Gaps and pseudogaps in perovskite rare earth nickelates. APL Materials, 2015, 3, 062503.	2.2	30
4	High-precision gigahertz-to-terahertz spectroscopy of aqueous salt solutions as a probe of the femtosecond-to-picosecond dynamics of liquid water. Journal of Chemical Physics, 2015, 142, 164502.	1.2	94
5	Small hole polarons in rare-earth titanates. Applied Physics Letters, 2015, 106, .	1.5	22
6	Two-Dimensional Electron Gases at Complex Oxide Interfaces. Annual Review of Materials Research, 2014, 44, 151-171.	4.3	154
7	Emergent Phenomena in Two-Dimensional Electron Gases at Oxide Interfaces. , 2013, , 49-49.	0	
8	Subband structure of two-dimensional electron gases in SrTiO ₃ . Applied Physics Letters, 2013, 103, 212103.	1.5	10
9	Conduction-band edge and Shubnikovâ€“de Haas effect in low-electron-density SrTiO ₃ . Physical Review B, 2013, 88, .	1.1	57
10	High-density Two-Dimensional Small Polaron Gas in a Delta-Doped Mott Insulator. Scientific Reports, 2013, 3, 3284.	1.6	25
11	Seebeck coefficient of a quantum confined, high-electron-density electron gas in SrTiO ₃ . Applied Physics Letters, 2012, 100, 161601.	1.5	15
12	Quantum oscillations from a two-dimensional electron gas at a Mott/band insulator interface. Applied Physics Letters, 2012, 101, .	1.5	33
13	Capacitance-voltage analysis of high-carrier-density SrTiO ₃ /GdTiO ₃ heterostructures. Applied Physics Letters, 2012, 100, 232106.	1.5	9
14	Toward an artificial Mott insulator: Correlations in confined high-density electron liquids in SrTiO ₃ . Physical Review B, 2012, 86, .	1.1	64
15	Carrier-Controlled Ferromagnetism in SrTiO ₃ . Physical Review X, 2012, 2, .	2.8	69
16	Growth and properties of GdTiO ₃ films prepared by hybrid molecular beam epitaxy. Journal of Crystal Growth, 2012, 355, 166-170.	0.7	39
17	Dielectric Spectroscopy of Proteins as a Quantitative Experimental Test of Computational Models of Their Low-Frequency Harmonic Motions. Journal of the American Chemical Society, 2011, 133, 8942-8947.	6.6	96
18	Electrostatic carrier doping of GdTiO ₃ /SrTiO ₃ interfaces. Applied Physics Letters, 2011, 99, .	1.5	214

#	ARTICLE	IF	CITATIONS
19	Transport in ferromagnetic GdTiO ₃ /SrTiO ₃ heterostructures. <i>Applied Physics Letters</i> , 2011, 98, .	1.5	60
20	A heterojunction modulation-doped Mott transistor. <i>Journal of Applied Physics</i> , 2011, 110, .	1.1	59
21	Novel Tunable Millimeter-Wave Grating-Gated Plasmonic Detectors. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , 2011, 17, 85-91.	1.9	34
22	Probing the metal-insulator transition of NdNiO ₃ by electrostatic doping. <i>Applied Physics Letters</i> , 2011, 99, .	1.5	39
23	Enhancing the electron mobility of SrTiO ₃ with strain. <i>Applied Physics Letters</i> , 2011, 98, .	1.5	77
24	Conductivity enhancement of ultrathin LaNiO ₃ films in superlattices. <i>Applied Physics Letters</i> , 2010, 97, .	1.5	59
25	Low-dimensional Mott material: Transport in ultrathin epitaxial LaNiO ₃ films. <i>Applied Physics Letters</i> , 2010, 96, .	1.5	189
26	Optical conductivity of LaNiO_3 . Coherent transport and correlation driven mass enhancement. <i>Physical Review B</i> , 2010, 82, .		
27	Terahertz detection in a multi-gate high electron mobility transistor. , 2009, .		0
28	Magnetostatic Spin-Wave Modes in Ferromagnetic Tube. <i>IEEE Transactions on Magnetics</i> , 2009, 45, 4223-4225.	1.2	8
29	Applications of Free-Electron Lasers in the Biological and Material Sciences ^{Å¶} . <i>Photochemistry and Photobiology</i> , 2005, 81, 711-735.	1.3	5
30	Nonequilibrium ac Josephson Effect in Mesoscopic Nb-InAs-Nb Junctions. <i>Physical Review Letters</i> , 1999, 82, 1265-1268.	2.9	40
31	Giant Magnetoresistance of Self-Assembled ErAs Islands in GaAs. <i>Materials Research Society Symposia Proceedings</i> , 1997, 475, 251.	0.1	12
32	Photoelectrochemical etching of high aspect ratio submillimeter waveguide filters fromn+GaAs wafers. <i>Applied Physics Letters</i> , 1992, 61, 2890-2892.	1.5	4